MAAL-010570

Low Noise Amplifier
0.1 - 3.5 GHz

Rev. V3

Features

- Single Voltage Supply 3V ~ 5V
- Integrated Active Bias Circuit
- Adjustable Current with an External Resistor
- Low Noise Figure
- High Linearity OIP3: 34.5 dBm @ 2 GHz
- Broadband Match
- Integrated ESD Protection
- RoHS* Compliant and 260°C Reflow Compatible

Description

The MAAL-010570 is a high dynamic range single stage MMIC LNA with excellent linearity and low noise figure designed for operation from 0.1 to 3.5 GHz. The LNA is packaged in an RoHS compliant SOT-363 package and requires no external matching components.

This MMIC has an integrated active bias circuit allowing direct connection to +3 V supply and minimizing variation over temperature and process. The bias current can be set with an external resistor to allow the user to customize the current value to fit the application.

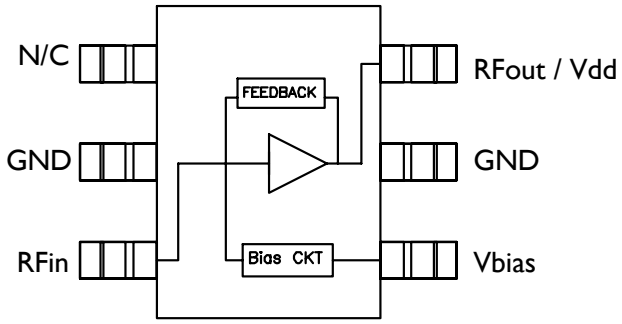
The MAAL-010570 offers less than 1 dB noise figure and 34.5 dBm OIP3 at 2 GHz. The broadband match and single supply operation makes this LNA easy to use and simplifies its implementation while maintaining excellent performance. The low thermal resistance and integrated ESD protection significantly enhances the quality, reliability and ruggedness of this product.

Ordering Information[1,2]

Part Number	Package
MAAL-010570-000000	bulk quantity
MAAL-010570-TR3000	3000 piece reel
MAAL-010570-001SMB	evaluation board (100 MHz ~ 3.5 GHz)

1. Reference Application Note M513 for reel size information.
2. All sample boards include 5 loose parts.

Functional Block Diagram



Pin Configuration[3]

Pin No.	Pin Name	Description
1	N/C	No Connection
2	GND	Ground
3	RF_{IN}	RF Input
4	V_{BIAS}	Bias Voltage
5	GND	Ground
6	RF_{OUT}	RF Output

3. It is recommended that all N/C (no connection) pins be grounded.

* Restrictions on Hazardous Substances, European Union Directive 2011/65/EU.

Low Noise Amplifier
0.1 - 3.5 GHz

Rev. V3

Typical Performance[4,5]: I_{DD} = 60 mA, I_{BIAS} = 8 mA, +25ºC

Parameter	Units	Typical Ratings								
V_{DD} = 3 V										
Frequency	GHz	0.2	0.5	0.8	1.0	1.5	2.0	2.5	3.0	3.5
Gain	dB	22.0	21.5	19.5	18.5	16.0	14.0	12.5	11.0	10.0
Output IP3	dBm	33.2	34.9	36.7	33.7	34.0	34.5	35.0	36.7	37.2
Output P1dB	dBm	17.0	18.0	18.6	18.3	18.8	19.1	19.0	19.1	18.4
Input Return Loss	dB	11.0	13.0	13.0	12.7	12.0	11.4	10.5	10.0	9.1
Output Return Loss	dB	19.0	26.0	23.0	22.0	20.5	20.5	20.0	19.5	20.0
Noise Figure	dB	0.70	0.80	0.75	0.74	0.75	0.84	0.93	1.10	1.20
V_{DD} = 5 V										
Frequency	GHz	0.2	0.5	0.8	1.0	1.5	2.0	2.5	3.0	3.5
Gain	dB	22.0	21.5	19.5	18.5	16.0	14.0	12.5	11.0	10.0
Output IP3	dBm	31.8	34.0	35.0	36.5	36.2	36.5	37.1	37.6	36.8
Output P1dB	dBm	22.0	21.0	22.0	21.9	22.2	22.2	22.4	22.4	22.1
Input Return Loss	dB	11.0	13.0	13.0	12.7	12.0	11.5	10.5	10.0	9.0
Output Return Loss	dB	22.0	26.0	20.0	19.0	17.5	17.0	17.0	16.5	17.0
Noise Figure	dB	0.80	0.84	0.80	0.78	0.80	0.90	1.0	1.16	1.28

4. Typical values presented in the above table were obtained by measurements using RF probes in a 50 Ω system.
5. P_{OUT} dBm, Tone Spacing = 1 MHz

Electrical Specifications[6,7]: 2 GHz (T_A = +25°C, V_{DD} = 3 V, Z_0 = 50 Ω)

Parameter	Units	Min.	Typ.	Max.
Small Signal Gain	dB	12.5	14.3	-
Output IP3	dBm	-	34.5	-
Output P1dB	dBm	17.0	18.6	-
Quiescent Current	mA	-	60.0	75.0
Noise Figure	dB	-	0.95	-

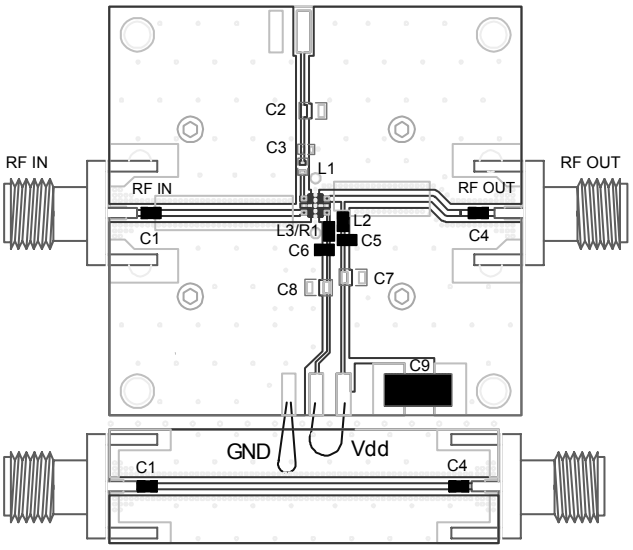
6. Unless otherwise specified, the specifications are guaranteed at room temperature in a MACOM test fixture.
7. Typical values presented in the above table are based on data from multiple wafer lots and evaluation board MAAL-010570-001SMB.

Absolute Maximum Ratings[8,9]

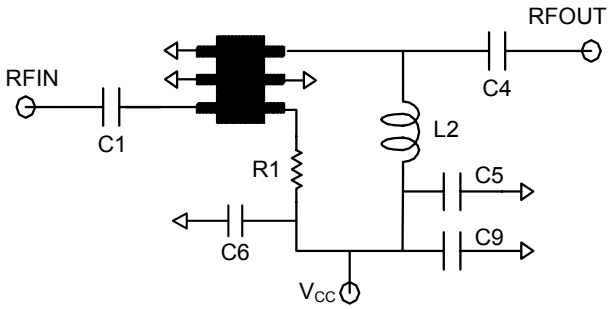
Parameter	Absolute Max.
Supply Voltage	5.5 V
Current	100 mA
Bias Current	15 mA
Power Dissipation	600 mW
RF Input Power	24 dBm
Storage Temperature	-55°C to +150°C
Operating Temperature	-40°C to +85°C
Junction Temperature	+150°C
Thermal Resistance	+104°C/W

8. Exceeding any one or combination of these limits may cause permanent damage to this device.
9. MACOM does not recommend sustained operation near these survivability limits.

Evaluation Board



Evaluation Board Schematic



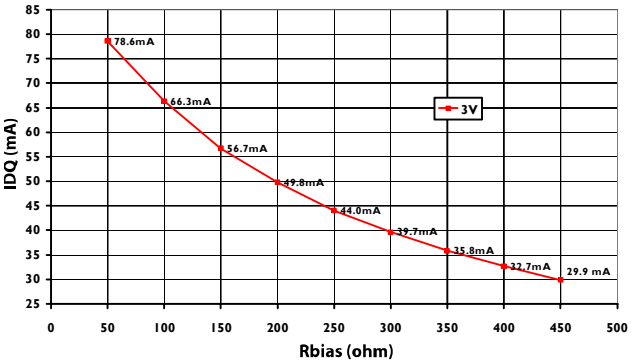
Component Values

Part	Value	Case Style
C1, C4, C5	1 nF	0402
C6	10 nF	0402
C9	100 µF tantalum	size C
L2	82 nH	0402
L3 or R1[10,]	Please refer to R_{BIAS} vs. I_{DQ} plot to select the appropriate R1 value	
C2, C3, C7, C8, L1, L3	Do not populate	

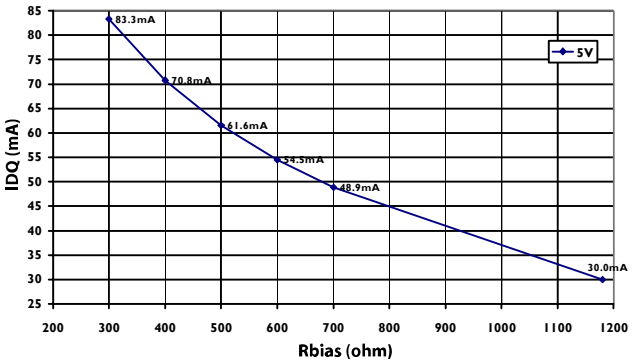
10. V_{BIAS} can be connected separate of V_{DD} to control the drain current. When V_{BIAS} is connected directly either a resistor is used to drop the voltage down from 3 V, or if the exact bias voltage (~2 V) is applied, then an inductor L3 can be used.

Typical Performance: R_{BIAS} vs. Current[11]

IDQ vs. R_{BIAS} @ 3 V



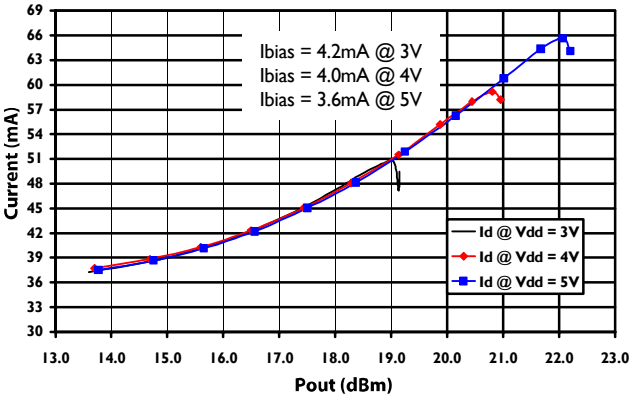
IDQ vs. R_{BIAS} @ 5 V



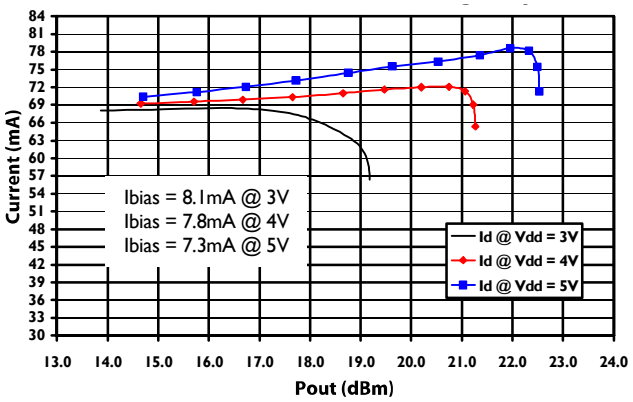
11. IDQ represents the total current of drain current (I_{DD}) and bias current (I_{BIAS}) combined. The resistor (R_{BIAS}) is connected between pin 4 (V_{BIAS}) and pin 6 (RF out / V_{DD}).

Typical Performance[12]: Total Current vs. P_{OUT} vs. Voltage

IDQ = 30 mA

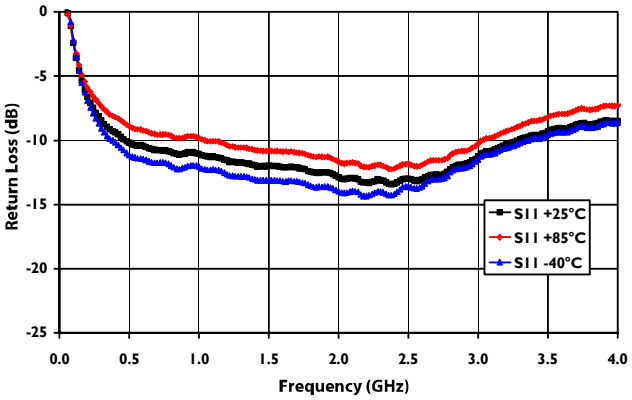


IDQ = 60 mA

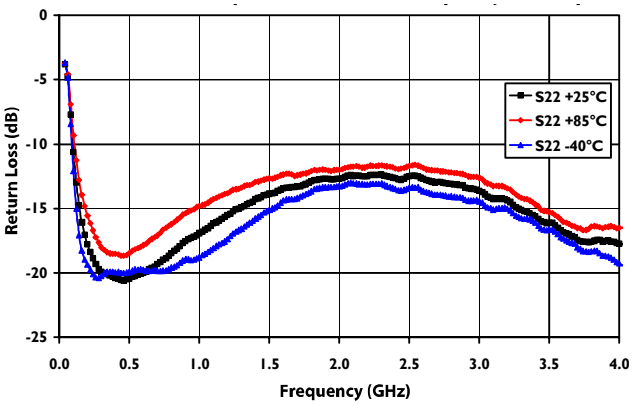


Typical Performance Curves[12]: 3 V, 30 mA (over temperature)

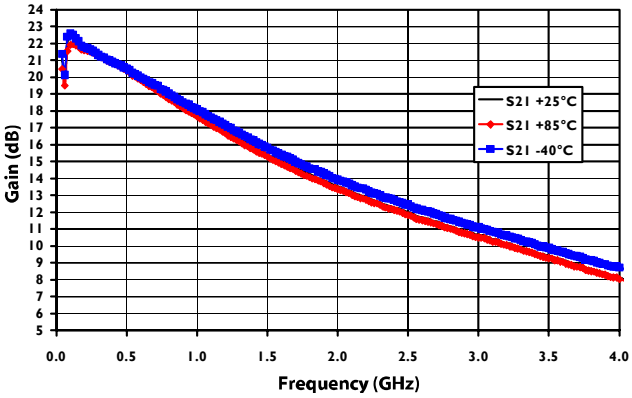
Input Return Loss



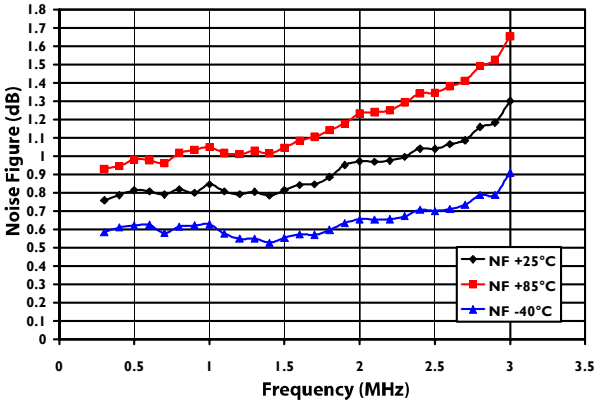
Output Return Loss



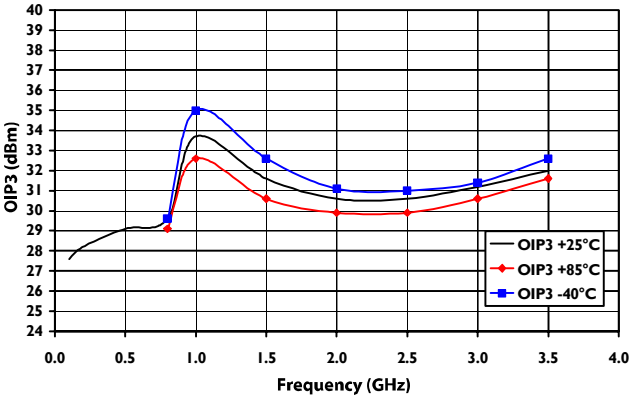
Gain



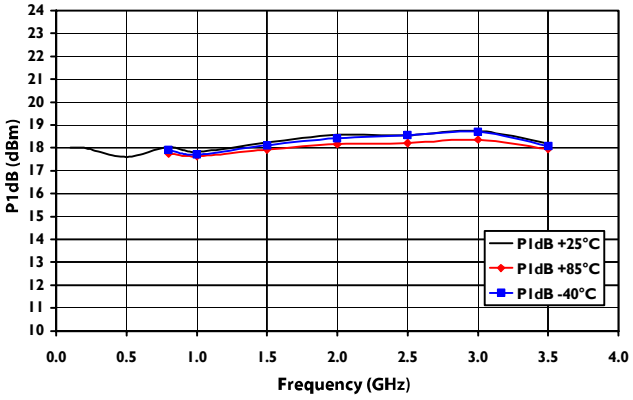
Noise Figure



OIP3

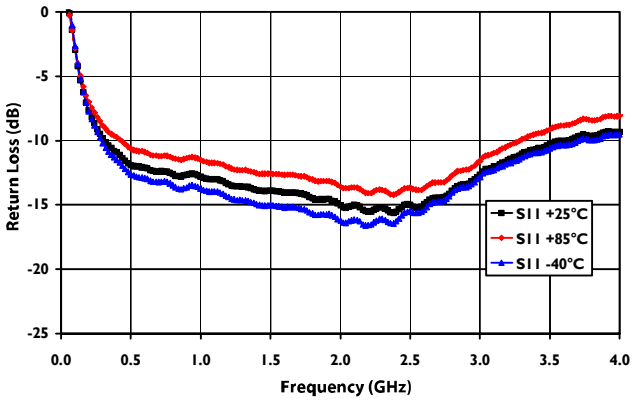


P1dB

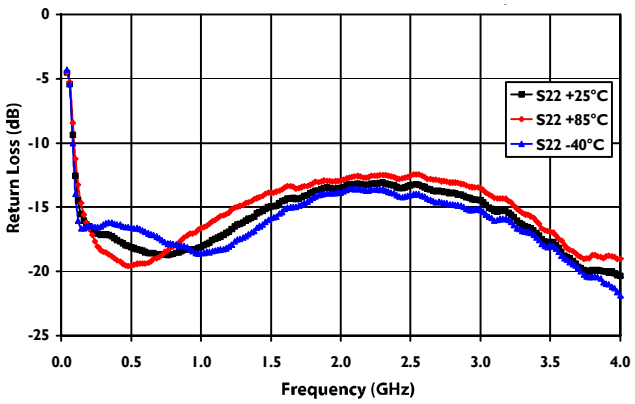


Typical Performance Curves[12]: 3 V, 60 mA (over temperature)

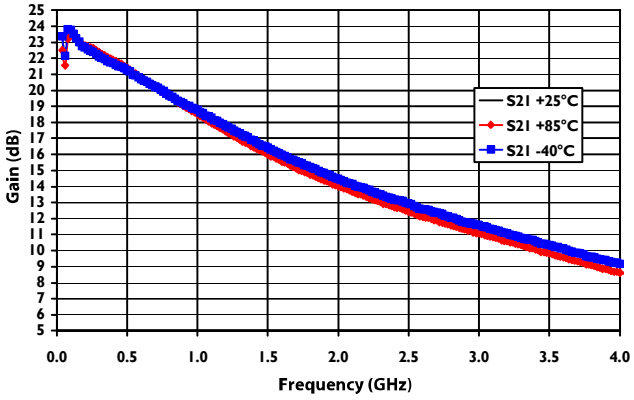
Input Return Loss



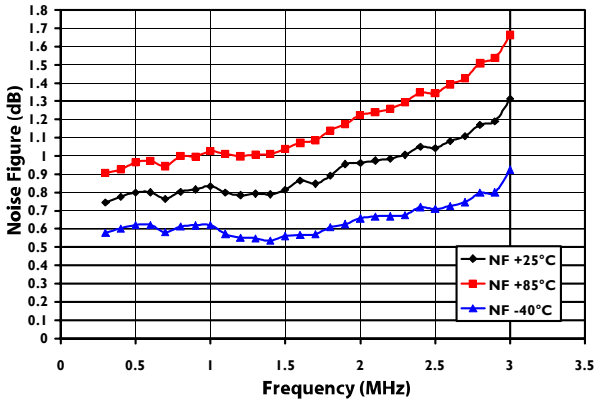
Output Return Loss



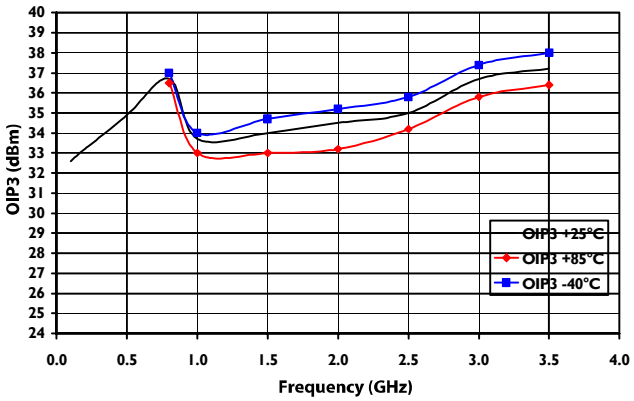
Gain



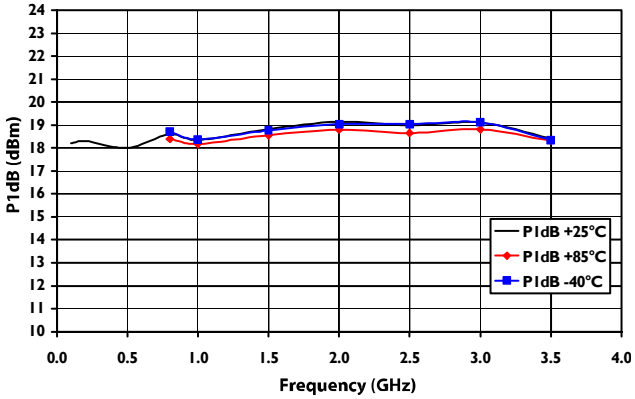
Noise Figure



OIP3

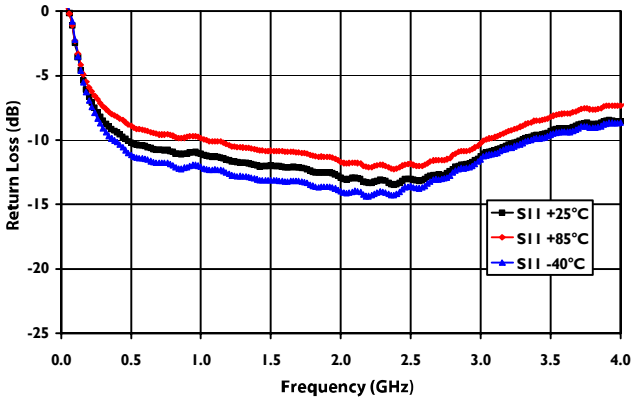


P1dB

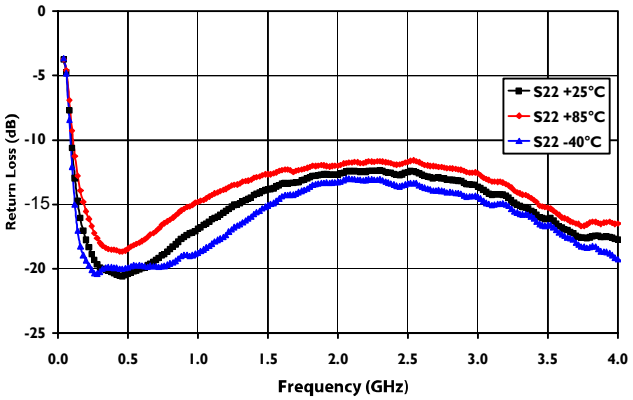


Typical Performance Curves[12]: 5 V, 30 mA (over temperature)

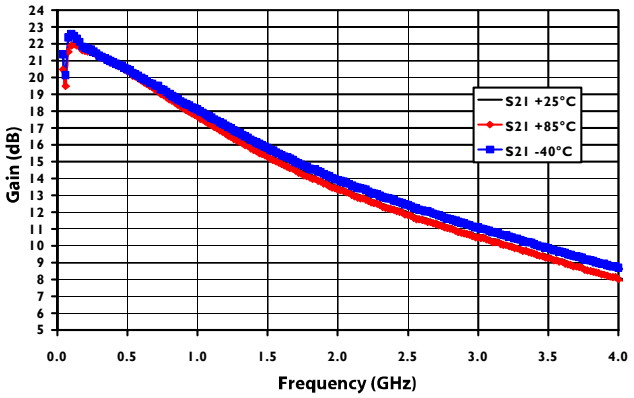
Input Return Loss



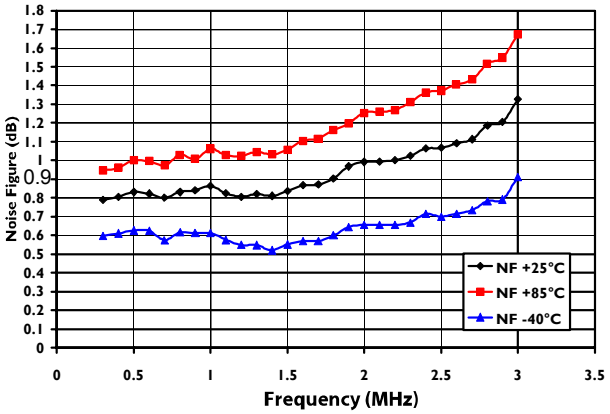
Output Return Loss



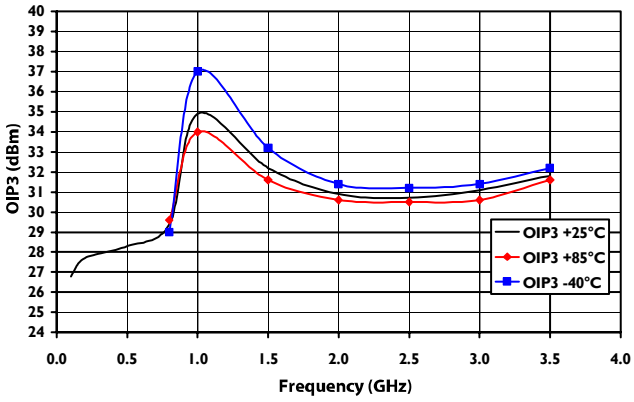
Gain



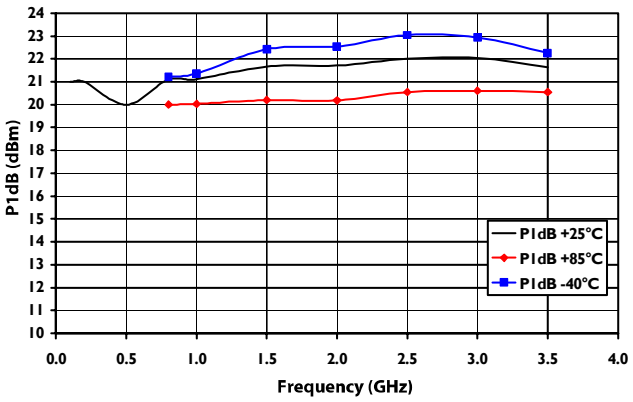
Noise Figure



OIP3

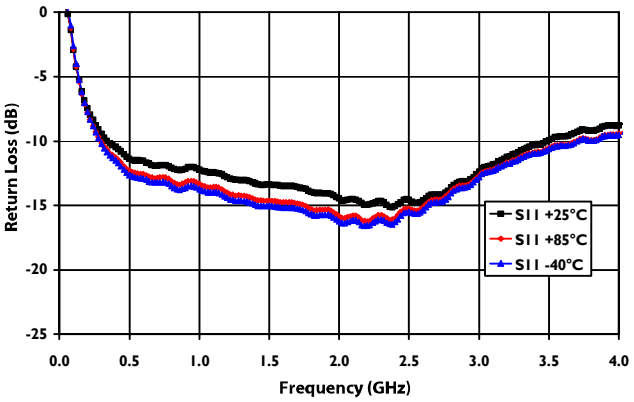


P1dB

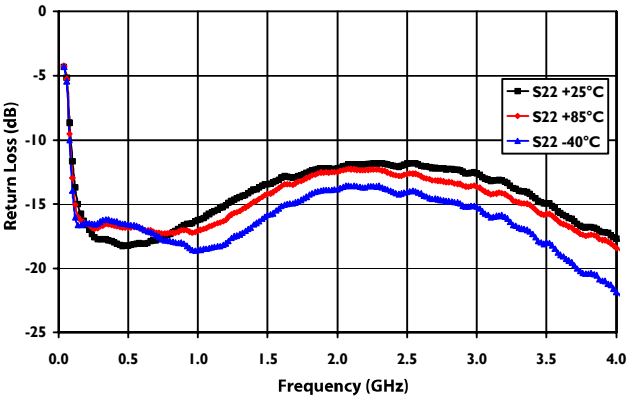


Typical Performance Curves[12]: 5 V, 60 mA (over temperature)

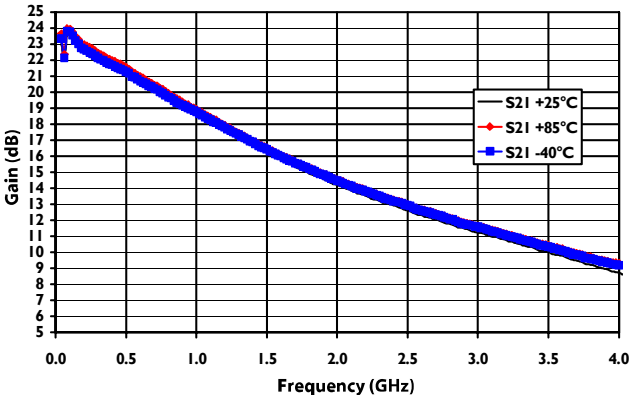
Input Return Loss



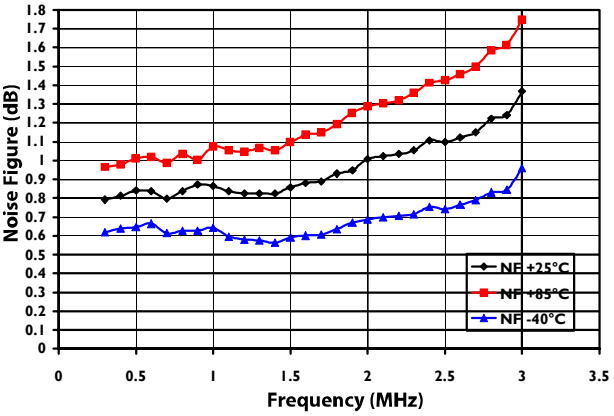
Output Return Loss



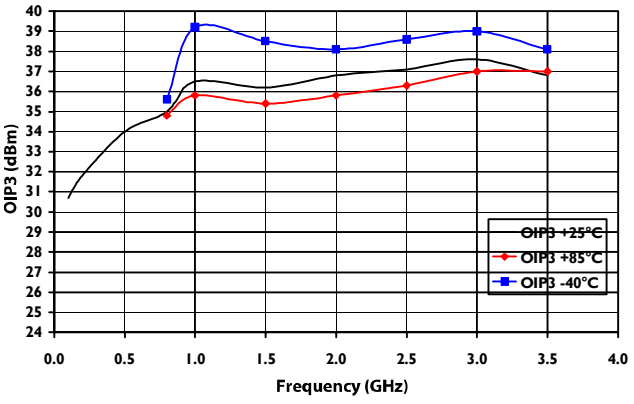
Gain



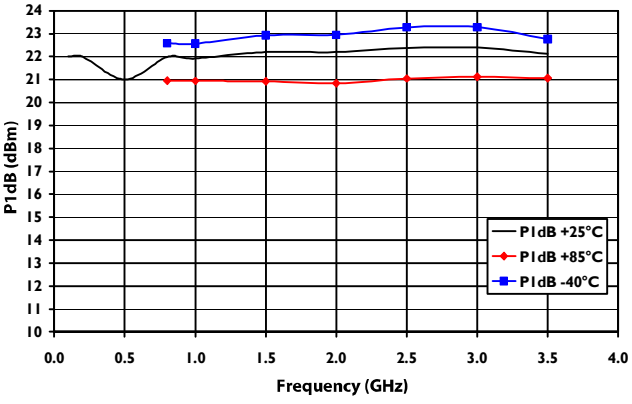
Noise Figure



OIP3



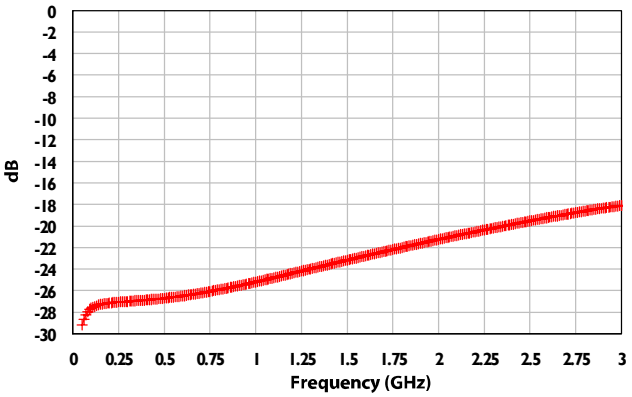
P1dB



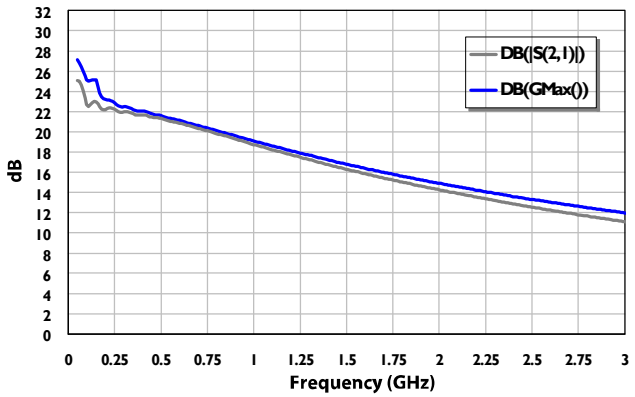
12. Graphs were generated using evaluation board MAAL-010570-001SMB.

Typical S-Parameters[13]

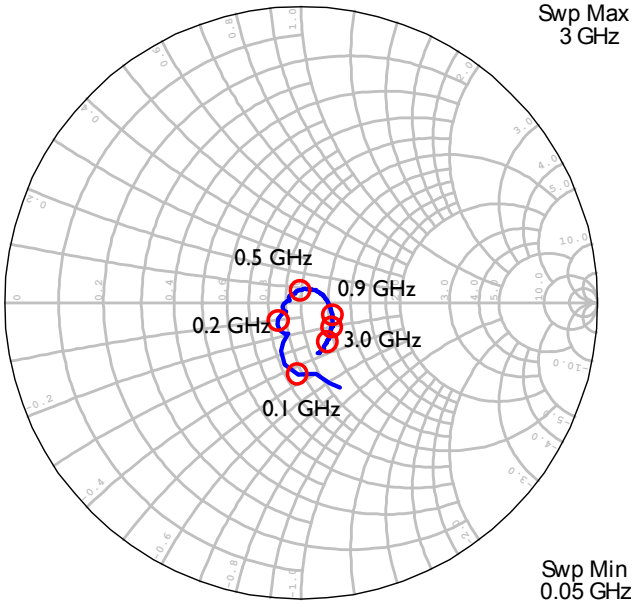
Reverse Isolation



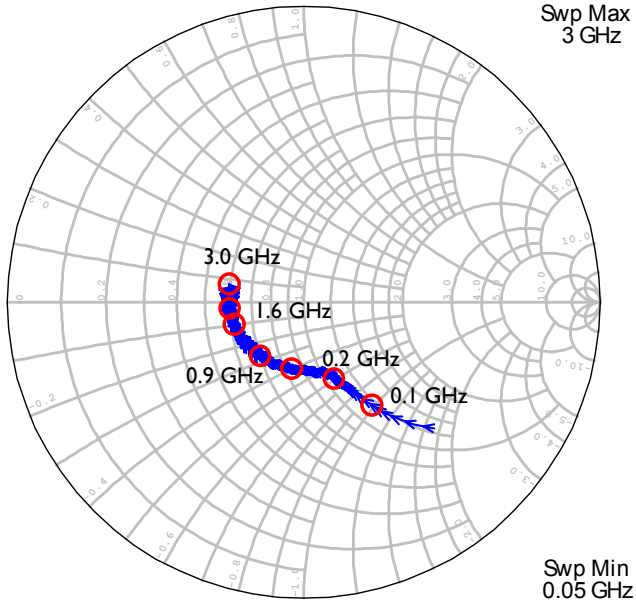
Gain



Output Return Loss

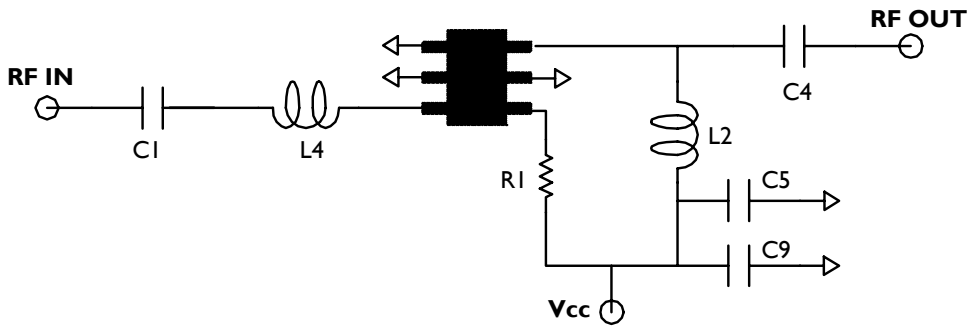


Input Return Loss



13. S-Parameters files in S2P format are available for download at macomtech.com.

Evaluation Board Schematic @ 100 MHz



Typical Performance: 3 V, 60 mA

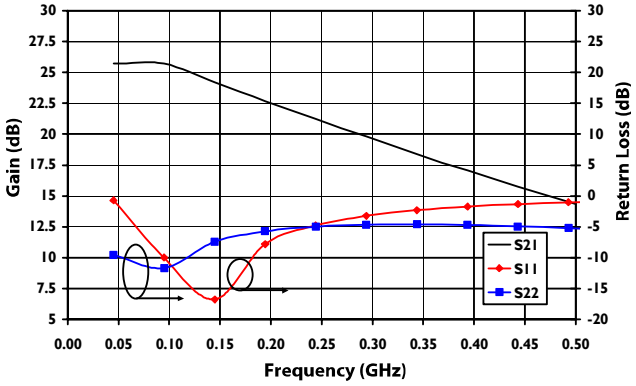
Parameter	Units	TYP
Frequency	GHz	0.1
Gain	dB	25.5
Output IP3[14]	dBm	31.5
Output P1dB	dBm	17.5
Input Return Loss	dB	11.0
Output Return Loss	dB	11.0
Noise Figure	dB	1.85

14. P_{OUT} = 5 dBm, Tone Spacing = 1 MHz

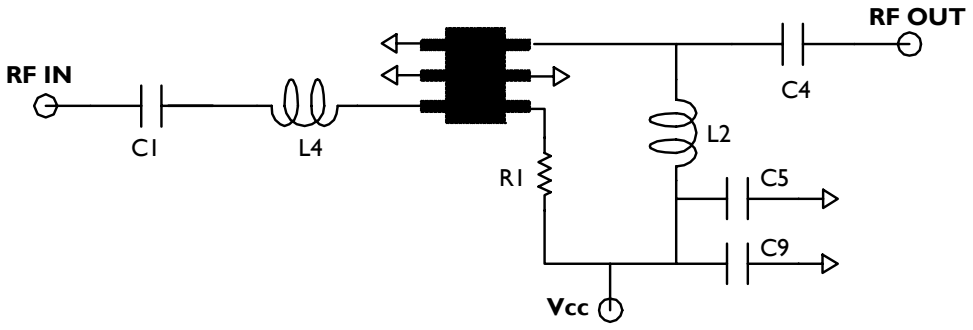
Component Values

Ref Designator	Description
C1, C4	1 nF 0402 Capacitor
C5	10 nF 0402 Capacitor
C9	100 µF Tantalum Capacitor Size C
L2	150 nH 0603 Inductor
L4	68 nH 0402 Inductor
R1	Refer to R_{BIAS} vs. I_{DD} plot
C2, C3, C6, C7, C8, L1, L3	DNP

S-Parameters using 100 MHz evaluation board



Evaluation Board Schematic @ 200 MHz



Typical Performance: 3 V, 60 mA

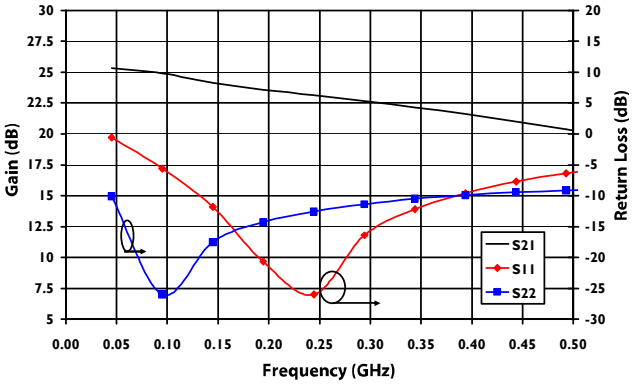
Parameter	Units	TYP
Frequency	GHz	0.2
Gain	dB	23.0
Output IP3[15]	dBm	33.5
Output P1dB	dBm	18.4
Input Return Loss	dB	20.0
Output Return Loss	dB	14.0
Noise Figure	dB	1.1

15. P_{OUT} = 5 dBm, Tone Spacing = 1 MHz

Component Values

Ref Designator	Description
C1, C4	1 nF 0402 Capacitor
C5	10 nF 0402 Capacitor
C9	100 µF Tantalum Capacitor Size C
L2	150 nH 0603 Inductor
L4	24 nH 0402 Inductor
R1	Refer to Rbias Vs Idd plot
C2, C3, C6, C7, C8, L1, L3	DNP

S-Parameters using 200 MHz evaluation board



Typical Noise Parameters: V_D = 3 V, +25ºC, Z_0 = 50 Ω

I_D = 20 mA

Freq (GHz)	NF_{min} (dB)	Γ_{opt} Mag.	Γ_{opt} Ang.	$R_{n/50}$	$NF_{50\,\Omega}$ (dB)
0.80	0.80	0.08	136.5	0.08	0.81
0.90	0.77	0.11	133.6	0.07	0.78
1.00	0.78	0.12	132.5	0.08	0.78
1.50	0.81	0.17	-176.6	0.06	0.82
2.00	0.88	0.31	-156.0	0.06	0.89
2.50	0.96	0.32	-139.3	0.08	0.97
3.00	1.12	0.35	-108.1	0.13	1.13
3.50	1.26	0.40	-93.6	0.19	1.28
4.00	1.33	0.43	-64.1	0.36	1.36

I_D = 30 mA

Freq (GHz)	NF_{min} (dB)	Γ_{opt} Mag.	Γ_{opt} Ang.	$R_{n/50}$	$NF_{50\,\Omega}$ (dB)
0.80	0.77	0.07	153.4	0.07	0.77
0.90	0.73	0.10	145.8	0.07	0.74
1.00	0.75	0.12	145.3	0.07	0.75
1.50	0.76	0.16	-168.2	0.07	0.76
2.00	0.84	0.31	-155.7	0.06	0.85
2.50	0.92	0.32	-135.2	0.08	0.93
3.00	1.07	0.32	-104.9	0.14	1.08
3.50	1.20	0.37	-92.3	0.20	1.21
4.00	1.29	0.44	-61.6	0.33	1.31

I_D = 60 mA

Freq (GHz)	NF_{min} (dB)	Γ_{opt} Mag.	Γ_{opt} Ang.	$R_{n/50}$	$NF_{50\,\Omega}$ (dB)
0.80	0.76	0.07	160.5	0.07	0.76
0.90	0.73	0.09	150.5	0.07	0.73
1.00	0.74	0.12	154.2	0.07	0.74
1.50	0.75	0.17	-158.5	0.07	0.76
2.00	0.84	0.29	-151.8	0.06	0.85
2.50	0.93	0.30	-129.9	0.08	0.94
3.00	1.09	0.31	-99.9	0.14	1.10
3.50	1.21	0.43	-88.5	0.19	1.22
4.00	1.31	0.44	-60.0	0.32	1.33

Typical Noise Parameters: V_D = 5 V, +25ºC, Z_0 = 50 Ω

I_D = 20 mA

Freq (GHz)	NF_{min} (dB)	Γ_{opt} Mag.	Γ_{opt} Ang.	$R_{n/50}$	$NF_{50\,\Omega}$ (dB)
0.80	0.81	0.08	135.0	0.08	0.81
0.90	0.78	0.11	132.0	0.08	0.78
1.00	0.78	0.11	129.4	0.08	0.79
1.50	0.81	0.17	-175.2	0.07	0.81
2.00	0.89	0.30	-161.9	0.06	0.89
2.50	0.97	0.32	-139.7	0.08	0.97
3.00	1.14	0.34	-109.3	0.14	1.15
3.50	1.23	0.40	-92.9	0.21	1.25
4.00	1.33	0.44	-65.7	0.34	1.36

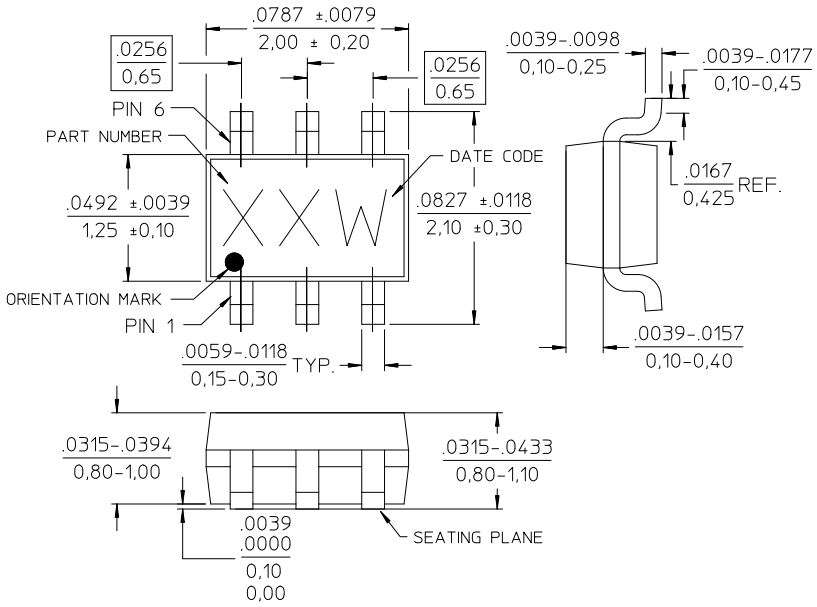
I_D = 30 mA

Freq (GHz)	NF_{min} (dB)	Γ_{opt} Mag.	Γ_{opt} Ang.	$R_{n/50}$	$NF_{50\,\Omega}$ (dB)
0.80	0.78	0.07	148.4	0.08	0.79
0.90	0.75	0.10	142.0	0.07	0.76
1.00	0.77	0.12	142.6	0.07	0.78
1.50	0.78	0.16	-165.7	0.07	0.79
2.00	0.87	0.30	-156.3	0.06	0.87
2.50	0.95	0.32	-135.2	0.08	0.96
3.00	1.10	0.32	-105.6	0.14	1.11
3.50	1.23	0.41	-89.1	0.20	1.25
4.00	1.31	0.47	-62.1	0.31	1.33

I_D = 60 mA

Freq (GHz)	NF_{min} (dB)	Γ_{opt} Mag.	Γ_{opt} Ang.	$R_{n/50}$	$NF_{50\,\Omega}$ (dB)
0.80	0.81	0.09	153.5	0.08	0.81
0.90	0.77	0.09	149.7	0.08	0.78
1.00	0.78	0.11	149.3	0.08	0.79
1.50	0.81	0.16	-160.0	0.07	0.81
2.00	0.90	0.30	-151.6	0.06	0.90
2.50	0.99	0.30	-130.2	0.09	1.00
3.00	1.16	0.31	-100.7	0.15	1.17
3.50	1.28	0.38	-88.1	0.23	1.30
4.00	1.37	0.43	-57.8	0.36	1.40

Lead-Free SC70-6LD (SOT-363)†



NOTES: 1. REFERENCE EIAJ SC-88 FOR ADDITIONAL DIMENSIONAL AND TOLERANCE INFORMATION.
2. REFERENCE M538 APPLICATION NOTE FOR PCB FOOTPRINT INFORMATION.
3. ALL DIMENSIONS SHOWN AS INCHES/MM.

† Reference Application Note M538 for lead-free solder reflow recommendations.
Meets JEDEC moisture sensitivity level 1 requirements.
Plating is 100% matte tin over copper.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these class 1A devices.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for macom ***manufacturer:***

Other Similar products are found below :

MAAM-000060-001SMB MAAM-011109-001SMB MAAP-010168-001SMB MAAP-010171-001SMB MAAP-011027-000SMB MAAP-015030-DIEEV1 MAAP-015030-DIEEV2 MAATCC0005-TB MAAVSS0001SMB MAAVSS0006SMB MABA-009210-CT17TB MACP-007727-CI07TB MAFC-010511-001SMB MAFX-999999-000 MAGX-001214-SB1PPR MAPS-010146-001SMB MASW-009444-001SMB MASWSS0130SMB MASWSS0143SMB MASWSS0157SMB MASWSS0179SMB MAADSS0008SMB MAAL-010528-000000 MAAL-010528-001SMB MAAL-010706-001SMB MAALSS0042SMB MAAP-010169-001SMB MAATSS0018SMB MABA-011002-TB MADP-007455-001SMB MAPRST0912-350 MASWSS0178SMB MASWSS0192SMB MASWSS0201SMB MC4507-2 XF1001-SC-EV1 XP1043-QH-EV1 SMA32 2087-6001-13 AT-233-PIN MY63C MY77 TP-104-PIN NPT25100B PB-CMM0511-QT-0000 DS-113-PIN CG1 AL7S MADC-011014-SMBPPR DU28120V